

CMOS Switched-Capacitor Voltage Converter

Features

- Simple conversion of V_{DD} to $-V_{\text{DD}}$
- Cascade connection (two devices are connected, $V_{OUT}\text{=}-2\;V_{DD})$
- Boost pin for higher switching frequency
- Easy to use
 Requires only two external capacitors

Applications

- RS-232 power supply
- · On board negative supply for dynamic RAMS
- Supply voltage splitter, V_O= \pm V_{DD}/2

- No external diode required
- Typically with no load voltage conversion, 99.9% efficiency
- Typical power efficiency is 98%
- Wide operating voltage range: 3V to 12V
- 8-pin DIP/SOP package
- Operation amplifier supply
- · Data acquisition systems
- · Positive voltage doubler

General Description

HT7660 is a monolithic CMOS switched-capacitor voltage converter. HT7660 is designed to complete a voltage conversion from positive to negative. The only required external components are two low cost electrolytic capacitors.

HT7660 includes a voltage regulator, an RC oscillator and four output power MOS switches. The frequency of

an RC oscillator can be lowered by adding an external capacitor between V_{DD} and the OSC pin, or an external clock can be connected to the OSC pin to replace the original oscillator. The LV terminal may be tied to VSS to disable the voltage regulator. By doing this, low voltage operation can be improved.





Pin Assignment

BOOST [1		C	
CAP+ 🗆	2	7 OS	С	
VSS 🗆	3	6 LV		
CAP-	4	5 VO	JT	
	LITZCC			
HI/000				
−8 DIP-A/SOP-A				

Pin Description

Pin No.	Pin Name	I/O	Internal Connection	Description	
1	BOOST	Ι	CMOS Pull-low	Higher switching frequency selection input	
2	CAP+	0	CMOS	This pin is connected to the positive terminal of Capacitor C1 for charge pump	
3	VSS			Negative power supply, ground	
4	CAP-	0	NMOS	This pin is connected to the negative terminal of Capacitor C1 fc charge pump	
5	VOUT	0	NMOS	This pin is connected to the negative terminal of Capacitor C2 charge reservoir. Output voltage pass through this pin	
6	LV	I		Floating this pin enables the voltage regulator. Connect this pin VSS (Ground) to bypass voltage regulator and improve low volta operation	
7	osc	I/O	Transmission Gate	External clock input pin. This pin can be connected with an extern capacitor to reduce switching frequency	
8	VDD	—		Positive power supply	

Absolute Maximum Ratings

Supply VoltageV_SS=0.3V to V_SS+13V Storage Temperature50°C to 125°C

Operating Temperature-40°C to 85°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Electrical Characteristics

Symphol	Devementer	Test Conditions		Min	Trees	Mex	11
Symbol	Parameter	V_{DD}	Conditions	wiin.	тур.	wax.	Unit
V _{DD}	Operating Voltage			3	_	12	V
1	Chan dhu Quimant	3V	No load	_	26	100	μA
I _{STB} Stand	Standby Current	5V		_	80	160	
f _{OSC} System Frequency		3V		2.5	4	_	kHz
	System Frequency	5V		5	10	_	
R _{OUT} Output Source Resistan	Output Source Desistance	3V	I _{OUT} =10mA	_	97	150	
	Jutput Source Resistance	5V	I _{OUT} =20mA	_	60	100	Ω
V _{CON-EFF} Vo	Voltage Conversion Efficiency	3V	No load	99	_	_	%
		5V		99	99.9	_	
D		3V	$-R_{L=}5k\Omega$	96			%
"EFF	Power Efficiency	5V		96	98		

Ta=25°C



Functional Description

HT7660 needs only two external polarized electrolytic capacitors to complete a negative voltage converter.

HT7660 has four MOS power switches: S1, S2, S3 and S4. For the first half cycle, when S2 and S4 are open, Capacitor C1 is charged to a voltage V_{DD} through S1 and S3. During the second half cycle, when S1 and S3 are open, the charge on Capacitor C1 is shifted to Capacitor C2 through S2 and S4. Thereby, the voltage across Capacitor C2 is V_{DD}. Because the positive terminal of C2 is connected to V_{SS}, we get a $-V_{DD}$ voltage at V_{OUT} pin.

For high voltage operation, the LV pin is left floating to enable the voltage regulator. This can reduce the current consumption of the RC oscillator, and thus get a fixed switching frequency f_{OSC} with high voltage range. For low voltage operation, the LV pin is connected to V_{SS} to bypass the voltage regulator of which inherent voltage drop can degrade the operation at low voltages.

A capacitor may be connected between V_{DD} and pin OSC to lower the switching f_{OSC} , and an external clock may be added to replace the built-in RC oscillator.



The operating mode of HT7660

Application Circuits

Simple Negative Voltage Converter









External Switching Frequency



Lower Switching Frequency



Note: Cosc is tens of pico farad

Positive Voltage Doubler



Note: VD is forward voltage drop of diode D1 and D2

Voltage Splitter





Combined Negative Voltage Converter and Positive Voltage Doubler



Note: VD is forward voltage drop of diode D1 and D2



Package Information

8-pin DIP (300mil) Outline Dimensions







Symbol	Dimensions in mil				
Symbol	Min.	Nom.	Max.		
A	355	—	375		
В	240	_	260		
С	125		135		
D	125		145		
E	16	_	20		
F	50	_	70		
G		100	—		
н	295	_	315		
1	335	—	375		
α	0°		15°		



8-pin SOP (150mil) Outline Dimensions







Symbol	Dimensions in mil				
Symbol	Min.	Nom.	Max.		
A	228	_	244		
В	149	_	157		
С	14	_	20		
C′	189		197		
D	53	_	69		
E		50	_		
F	4	_	10		
G	22	_	28		
Н	4		12		
α	0°		10°		



Product Tape and Reel Specfications

Reel Dimensions



SOP 8N

Symbol	Description	Dimensions in mm
А	Reel Outer Diameter	330±1.0
В	Reel Inner Diameter	62±1.5
с	Spindle Hole Diameter	13.0+0.5 _0.2
D	Key Slit Width	2.0±0.15
T1	Space Between Flange	12.8+0.3 0.2
T2	Reel Thickness	18.2±0.2



Carrier Tape Dimensions



SOP 8N

Symbol	Description	Dimensions in mm
w	Carrier Tape Width	12.0+0.3 0.1
Р	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	5.5±0.1
D	Perforation Diameter	1.55±0.1
D1	Cavity Hole Diameter	1.5+0.25
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	6.4±0.1
В0	Cavity Width	5.20±0.1
К0	Cavity Depth	2.1±0.1
t	Carrier Tape Thickness	0.3±0.05
С	Cover Tape Width	9.3



Holtek Semiconductor Inc. (Headquarters)

No.3, Creation Rd. II, Science Park, Hsinchu, Taiwan Tel: 886-3-563-1999 Fax: 886-3-563-1189 http://www.holtek.com.tw

Holtek Semiconductor Inc. (Taipei Sales Office)

4F-2, No. 3-2, YuanQu St., Nankang Software Park, Taipei 115, Taiwan Tel: 886-2-2655-7070 Fax: 886-2-2655-7373 Fax: 886-2-2655-7383 (International sales hotline)

Holtek Semiconductor Inc. (Shanghai Sales Office)

7th Floor, Building 2, No.889, Yi Shan Rd., Shanghai, China 200233 Tel: 021-6485-5560 Fax: 021-6485-0313 http://www.holtek.com.cn

Holtek Semiconductor Inc. (Shenzhen Sales Office) 43F, SEG Plaza, Shen Nan Zhong Road, Shenzhen, China 518031 Tel: 0755-8346-5589 Fax: 0755-8346-5590 ISDN: 0755-8346-5591

Holtek Semiconductor Inc. (Beijing Sales Office)

Suite 1721, Jinyu Tower, A129 West Xuan Wu Men Street, Xicheng District, Beijing, China 100031 Tel: 010-6641-0030, 6641-7751, 6641-7752 Fax: 010-6641-0125

Holmate Semiconductor, Inc. (North America Sales Office)

46712 Fremont Blvd., Fremont, CA 94538 Tel: 510-252-9880 Fax: 510-252-9885 http://www.holmate.com

Copyright © 2003 by HOLTEK SEMICONDUCTOR INC.

The information appearing in this Data Sheet is believed to be accurate at the time of publication. However, Holtek assumes no responsibility arising from the use of the specifications described. The applications mentioned herein are used solely for the purpose of illustration and Holtek makes no warranty or representation that such applications will be suitable without further modification, nor recommends the use of its products for application that may present a risk to human life due to malfunction or otherwise. Holtek's products are not authorized for use as critical components in life support devices or systems. Holtek reserves the right to alter its products without prior notification. For the most up-to-date information, please visit our web site at http://www.holtek.com.tw.